

Six-Pack XPT IGBT

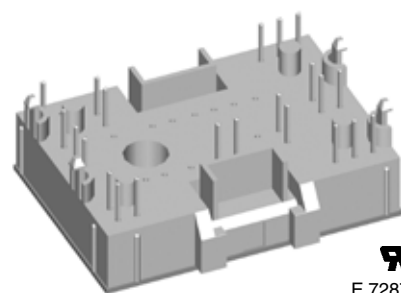
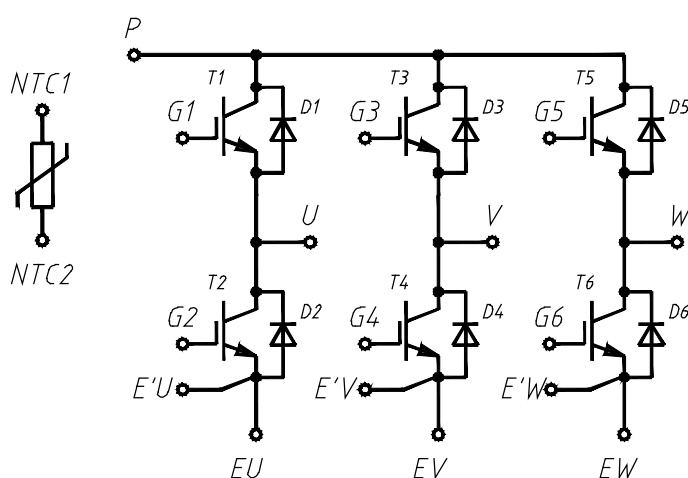
$$V_{CES} = 1200 \text{ V}$$

$$I_{C25} = 60 \text{ A}$$

$$V_{CE(sat)} = 1.8 \text{ V}$$

Part name (Marking on product)

MIXA40W1200TMH



UL
E 72873

Pin configuration see outlines.

Features:

- High level of integration - only one power semiconductor module required for the whole drive
- Rugged XPT design (Xtreme light Punch Through) results in:
 - short circuit rated for 10 μ sec.
 - very low gate charge
 - square RBSOA @ 3x I_C
 - low EMI
- Thin wafer technology combined with the XPT design results in a competitive low $V_{CE(sat)}$
- Temperature sense included
- SONIC™ diode
 - fast and soft reverse recovery
 - low operating forward voltage

Application:

- AC motor drives
- Pumps, Fans
- Washing machines
- Air-conditioning system
- Inverter and power supplies

Package:

- "Mini" package
- Assembly height is 17 mm
- Insulated base plate
- Pins suitable for wave soldering and PCB mounting
- Assembly clips available
 - IXKU 5-505 screw clamp
 - IXRB 5-506 click clamp
- UL registered E72873

Output Inverter T1 - T6

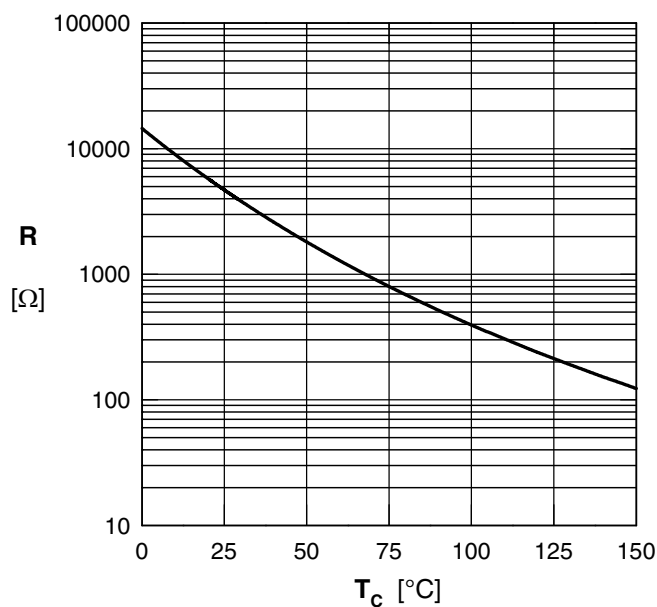
Symbol	Definitions	Conditions	min.	Ratings			
				typ.	max.	Unit	
V_{CES}	collector emitter voltage	$T_{VJ} = 25^{\circ}\text{C}$			1200	V	
V_{GES}	max. DC gate voltage	continuous			± 20	V	
V_{GEM}	max. transient collector gate voltage	transient			± 30	V	
I_{C25}	collector current	$T_C = 25^{\circ}\text{C}$			60	A	
I_{C80}		$T_C = 80^{\circ}\text{C}$			40	A	
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$			195	W	
$V_{CE(sat)}$	collector emitter saturation voltage	$I_C = 35\text{ A}; V_{GE} = 15\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	1.8 2.1	2.1	V V	
$V_{GE(th)}$	gate emitter threshold voltage	$I_C = 1.5\text{ mA}; V_{GE} = V_{CE}$	$T_{VJ} = 25^{\circ}\text{C}$	5.4	5.9	6.5	V
I_{CES}	collector emitter leakage current	$V_{CE} = V_{CES}; V_{GE} = 0\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	0.02 0.3	0.15	mA mA	
I_{GES}	gate emitter leakage current	$V_{GE} = \pm 20\text{ V}$			500	nA	
$Q_{G(on)}$	total gate charge	$V_{CE} = 600\text{ V}; V_{GE} = 15\text{ V}; I_C = 35\text{ A}$		106		nC	
$t_{d(on)}$	turn-on delay time	inductive load $V_{CE} = 600\text{ V}; I_C = 35\text{ A}$ $V_{GE} = \pm 15\text{ V}; R_G = 27\text{ }\Omega$	$T_{VJ} = 125^{\circ}\text{C}$	70		ns	
t_r	current rise time			40		ns	
$t_{d(off)}$	turn-off delay time			250		ns	
t_f	current fall time			100		ns	
E_{on}	turn-on energy per pulse			3.8		mJ	
E_{off}	turn-off energy per pulse			4.1		mJ	
RBSOA	reverse bias safe operating area	$V_{GE} = \pm 15\text{ V}; R_G = 27\text{ }\Omega; V_{CEK} = 1200\text{ V}$ $T_{VJ} = 125^{\circ}\text{C}$			105	A	
I_{SC} (SCSOA)	short circuit safe operating area	$V_{CE} = 900\text{ V}; V_{GE} = \pm 15\text{ V};$ $R_G = 27\text{ }\Omega; t_p = 10\text{ }\mu\text{s};$ non-repetitive	$T_{VJ} = 125^{\circ}\text{C}$	140		A	
R_{thJC}	thermal resistance junction to case	(per IGBT)			0.64	K/W	
R_{thCH}	thermal resistance case to heatsink			0.21		K/W	

Output Inverter D1 - D6

					Ratings		
Symbol	Definitions	Conditions	min.	typ.	max.	Unit	
V_{RRM}	<i>max. repetitive reverse voltage</i>		$T_{VJ} = 25^{\circ}\text{C}$		1200	V	
I_{F25}	<i>forward current</i>		$T_C = 25^{\circ}\text{C}$		44	A	
I_{F80}			$T_C = 80^{\circ}\text{C}$		29	A	
V_F	<i>forward voltage</i>	$I_F = 30\text{ A}; V_{GE} = 0\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$	1.95 1.95	2.2	V V	
Q_{rr}	<i>reverse recovery charge</i>	$\left. \begin{array}{l} V_R = 600\text{ V} \\ di_F/dt = -600\text{ A}/\mu\text{s} \\ I_F = 30\text{ A}; V_{GE} = 0\text{ V} \end{array} \right\}$	$T_{VJ} = 125^{\circ}\text{C}$	3.5		μC	
I_{RM}	<i>max. reverse recovery current</i>			30		A	
t_{rr}	<i>reverse recovery time</i>			350		ns	
E_{rec}	<i>reverse recovery energy</i>			0.9		mJ	
R_{thJC}	<i>thermal resistance junction to case</i>	(per diode)			1.2	K/W	
R_{thCH}	<i>thermal resistance case to heatsink</i>			0.4		K/W	

Temperature Sensor NTC

Symbol	Definitions	Conditions	Ratings			
			min.	typ.	max.	Unit
R_{25}	resistance	$T_C = 25^\circ\text{C}$	4.75	5.0	5.25	k Ω
$B_{25/50}$				3375		K

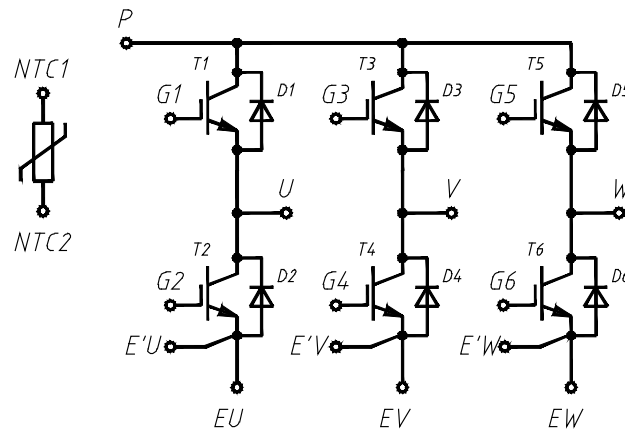


Typ. NTC resistance vs. temperature

Module

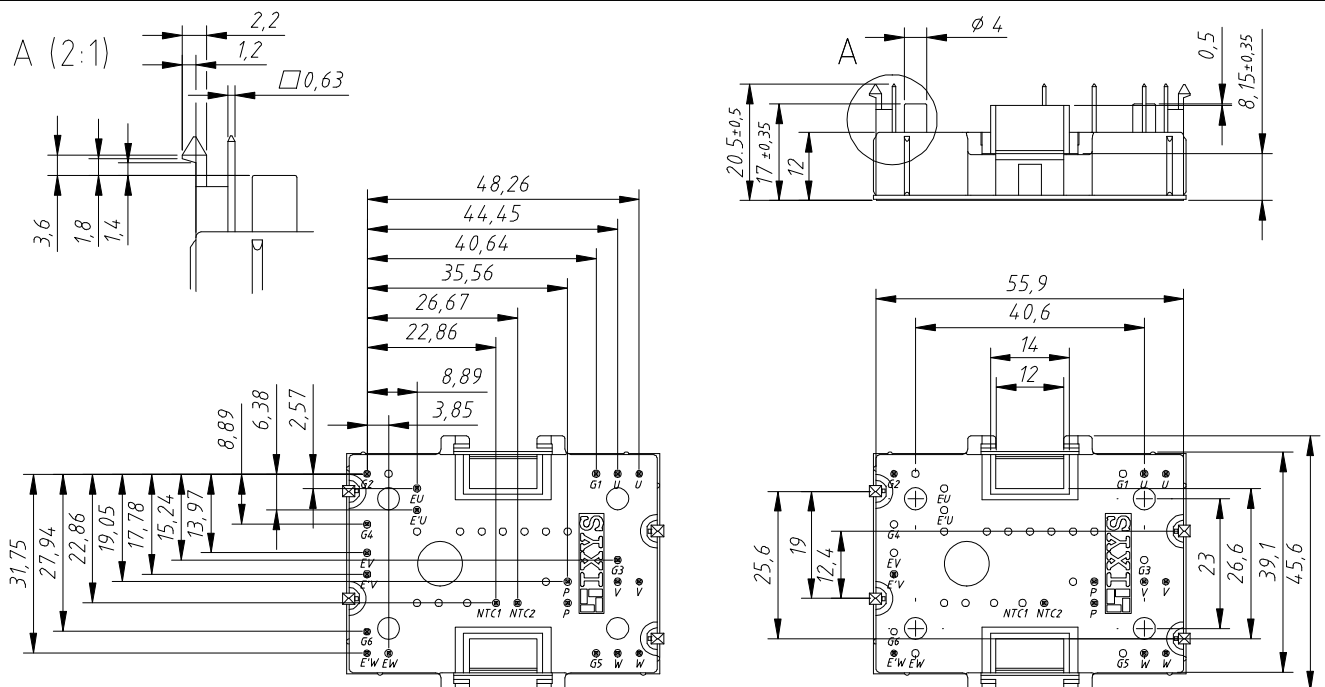
Symbol	Definitions	Conditions	Ratings			
			min.	typ.	max.	Unit
T_{VJ}	operating temperature		-40		125	$^\circ\text{C}$
T_{VJM}	max. virtual junction temperature				150	$^\circ\text{C}$
T_{stg}	storage temperature		-40		125	$^\circ\text{C}$
V_{ISOL}	isolation voltage	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$			2500	V~
CTI	comparative tracking index				-	
F_C	mounting force		40		80	N
d_s	creep distance on surface		12.7			mm
d_A	strike distance through air		12			mm
Weight				35		g

Circuit Diagram



Outline Drawing

Dimensions in mm (1 mm = 0.0394")

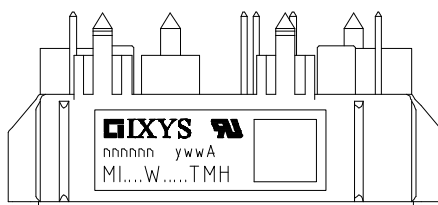


Bemerkungen:

- 1) Toleranz für Pin Positionen entsprechend ± 0.4
- 2) Vorgesehen für die Montage auf Leiterplatten mit einer Dicke von 1.6 ± 0.2 mm

Remarks:

- 1.) pin positions with tolerance ± 0.4
- 2) mounting on PCB with thickness of 1.6 ± 0.2 mm



Part number

M = Module
I = IGBT
X = XPT
A = standard
40 = Current Rating [A]
W = 6-Pack
1200 = Reverse Voltage [V]
T = NTC
MH = MiniPack2

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Ordering Code
Standard	MIXA 40 W 1200 TMH	MIXA40W1200TMH	Box	20	509395

IGBT T1 - T6

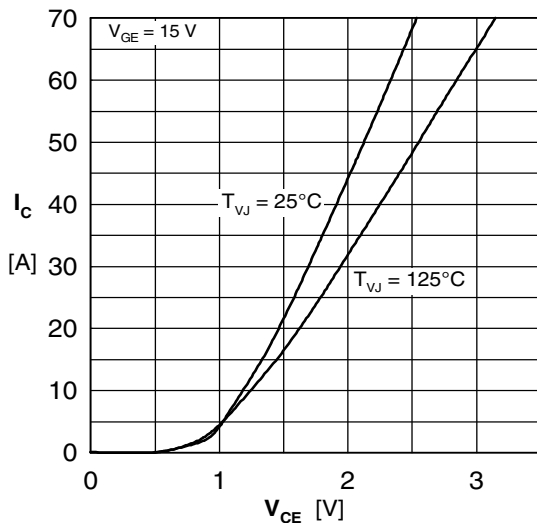


Fig. 1 Typ. output characteristics

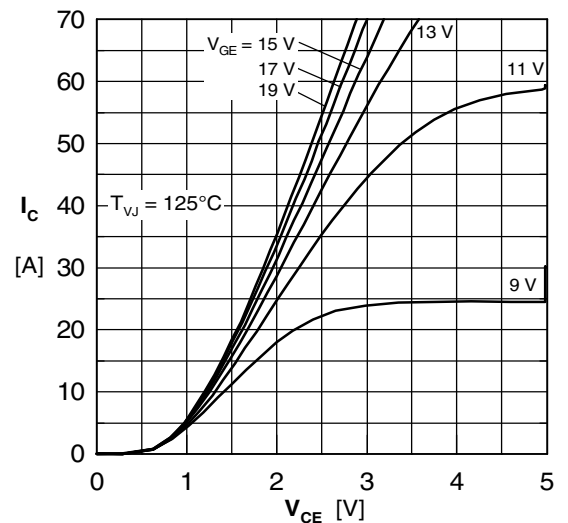


Fig. 2 Typ. output characteristics

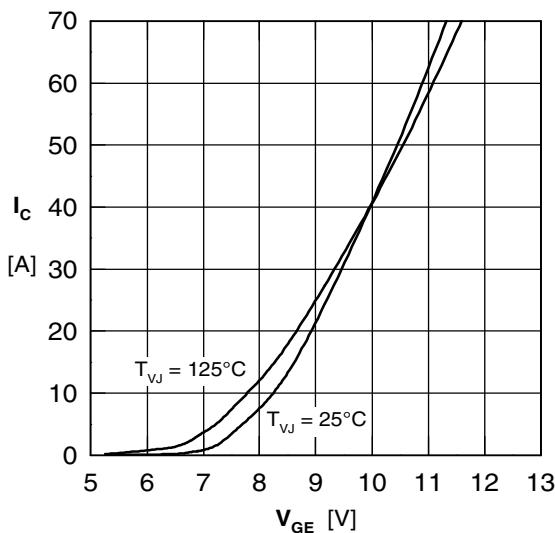


Fig. 3 Typ. transfer characteristics

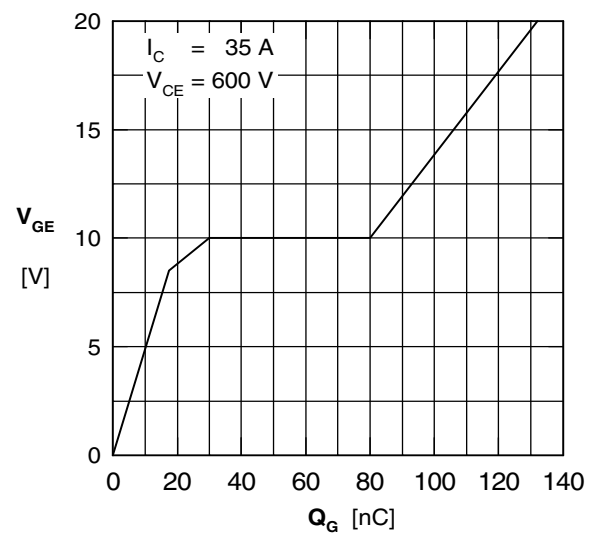


Fig. 4 Typ. turn-on gate charge

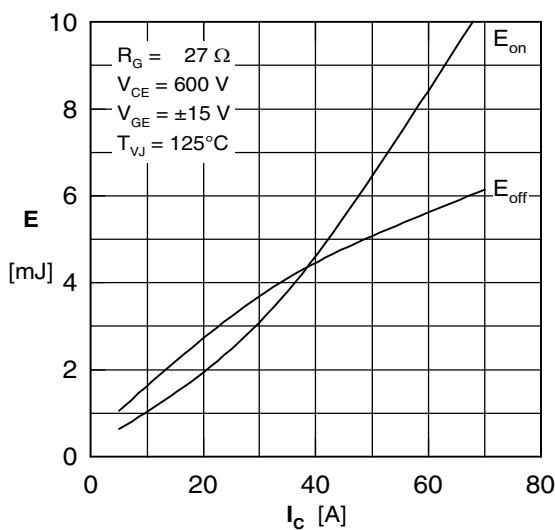


Fig. 5 Typ. switching energy vs. collector current

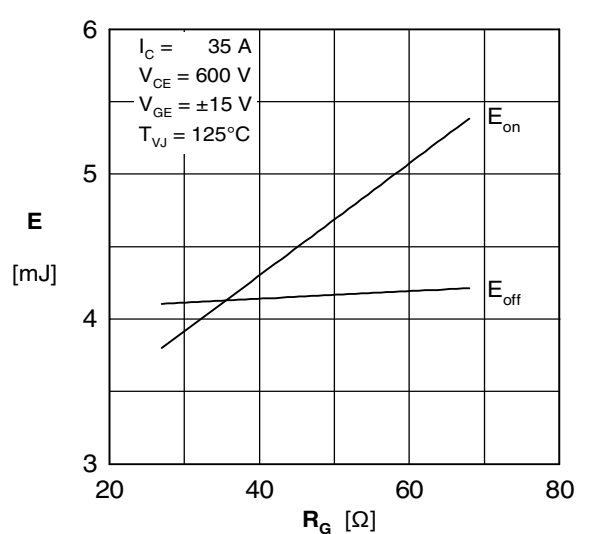


Fig. 6 Typ. switching energy vs. gate resistance

Diode D1 - D6

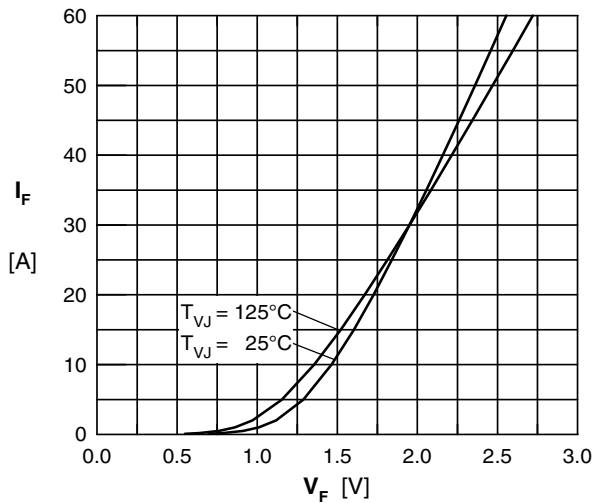


Fig. 7 Typ. Forward current versus V_F

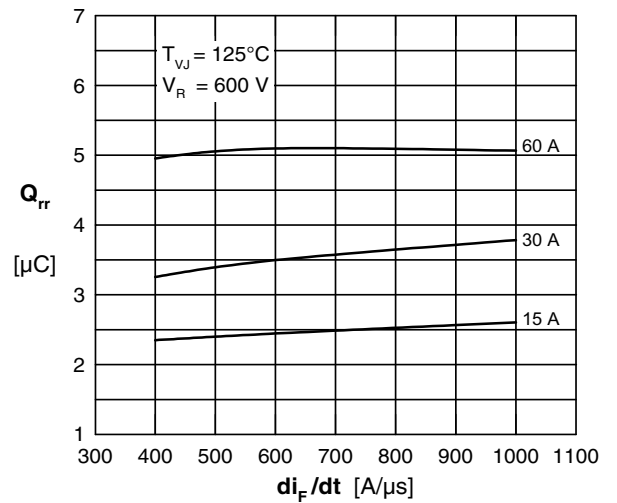


Fig. 8 Typ. reverse recov.charge Q_{rr} vs. di/dt

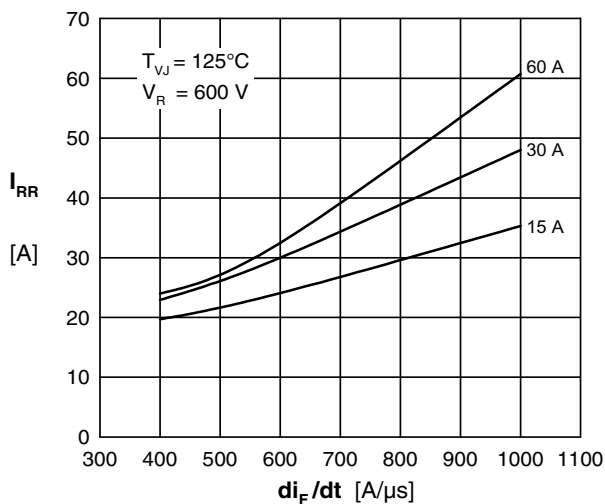


Fig. 9 Typ. peak reverse current I_{RM} vs. di/dt

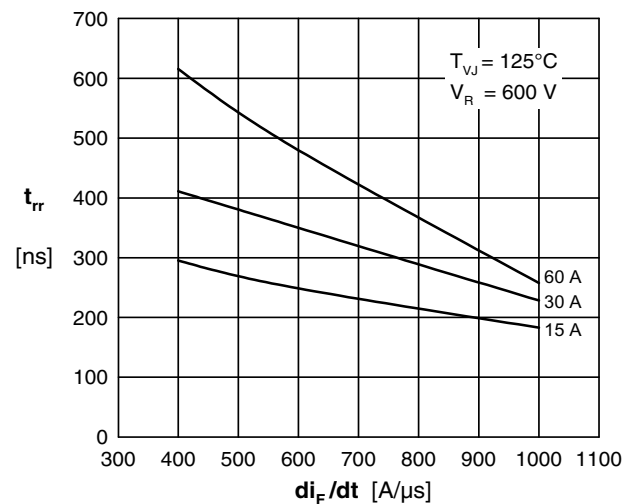


Fig. 10 Typ. recovery time t_{rr} versus di/dt

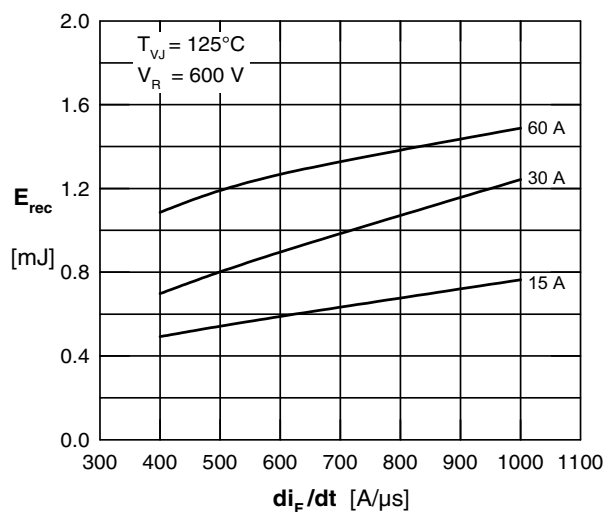


Fig. 11 Typ. recovery energy E_{rec} versus di/dt

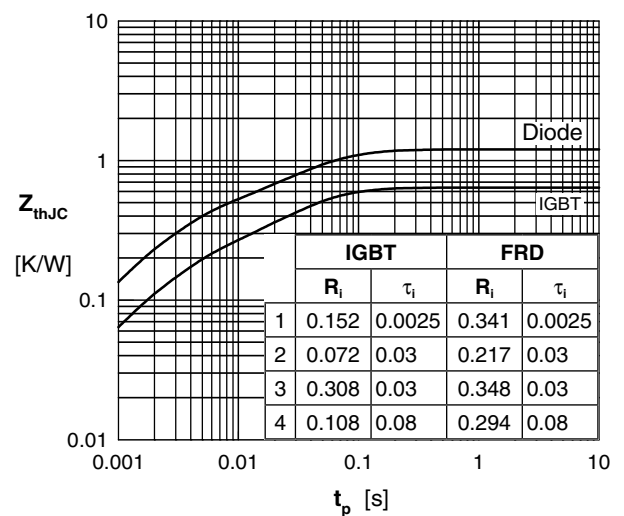


Fig. 12 Typ. transient thermal impedance

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